

## High-Power Density 2W Laser Diode

### Description

The SLD324ZT is a gain-guided, high-power density laser diode with a built-in TE cooler. A new flat, square package with a low thermal resistance and an in-line pin configuration is employed. Fine tuning of the wavelength is possible by controlling the laser chip temperature.

### Features

- High power  
Recommended optical power output:  $P_o = 2.0W$
- Low operating current:  $I_{op} = 2.5A$  ( $P_o = 2.0W$ )
- Newly developed flat package with built-in photodiode, TE cooler and thermistor

### Applications

- Solid state laser excitation
- Medical use
- Material processes
- Measurement

### Structure

GaAlAs quantum well structure laser diode

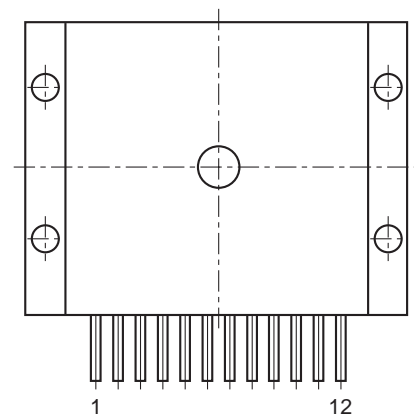
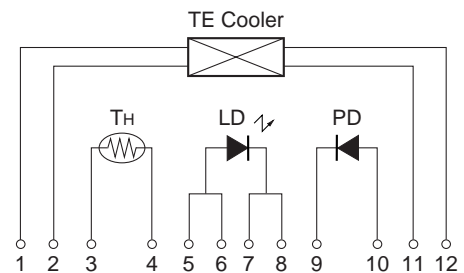
### Absolute Maximum Ratings ( $T_{th} = 25^{\circ}C$ )

- |                                      |           |            |             |
|--------------------------------------|-----------|------------|-------------|
| • Optical power output               | $P_o$     | 2.2        | W           |
| • Reverse voltage                    | $V_R$ LD  | 2          | V           |
|                                      | PD        | 15         | V           |
| • Operating temperature ( $T_{th}$ ) | $T_{opr}$ | -10 to +30 | $^{\circ}C$ |
| • Storage temperature                | $T_{stg}$ | -40 to +85 | $^{\circ}C$ |
| • Operating current of TE cooler     | $I_T$     | 4.0        | A           |

### Pin Configuration (Top View)

No.	Function	No.	Function
1	TE Cooler (negative)	7	LD (cathode)
2	TE Cooler (negative)	8	LD (cathode)
3	Thermistor	9	PD (cathode)
4	Thermistor	10	PD (anode)
5	LD (anode)	11	TE Cooler (positive)
6	LD (anode)	12	TE Cooler (positive)

### Equivalent Circuit



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**Electrical and Optical Characteristics**

(Tth: Thermistor temperature, Tth = 25°C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Threshold current	Ith			0.6	1.0	A	
Operating current	Iop	P <sub>O</sub> = 2.0W		2.5	3.5	A	
Operating voltage	Vop	P <sub>O</sub> = 2.0W		2.2	3.0	V	
Wavelength*1	λp	P <sub>O</sub> = 2.0W	790		840	nm	
Monitor current	I <sub>mon</sub>	P <sub>O</sub> = 2.0W V <sub>R</sub> = 10V	0.15	0.8	3.0	mA	
Radiation angle (F. W. H. M.*)	Perpendicular	θ <sub>⊥</sub>	P <sub>O</sub> = 2.0W	20	30	40	degree
	Parallel			θ <sub>//</sub>	4	9	17
Positional accuracy	Position	ΔX, ΔY	P <sub>O</sub> = 2.0W			±100	μm
	Angle	Δφ <sub>⊥</sub>				±3	degree
Differential efficiency	η <sub>D</sub>	P <sub>O</sub> = 2.0W	0.65	1.0		W/A	
Thermistor resistance	R <sub>th</sub>	T <sub>th</sub> = 25°C		10		kΩ	

\* F. W. H. M. : Full Width at Half Maximum

**\*1 Wavelength Selection Classification**

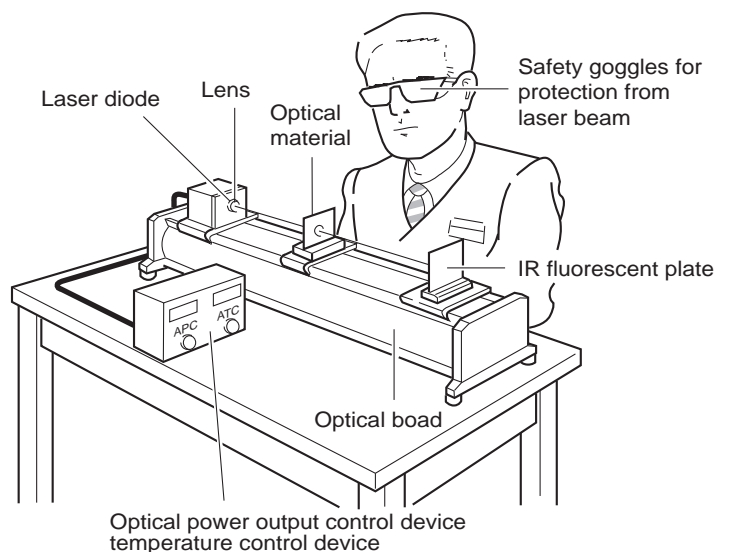
Type	Wavelength (nm)
SLD324ZT-1	795 ± 5
SLD324ZT-2	810 ± 10
SLD324ZT-3	830 ± 10

Type	Wavelength (nm)
SLD324ZT-21	798 ± 3
SLD324ZT-24	807 ± 3
SLD324ZT-25	810 ± 3

**Handling Precautions**

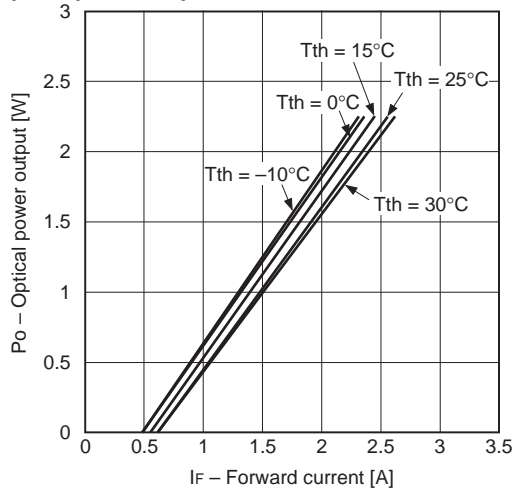
Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 3W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm<sup>2</sup>. Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

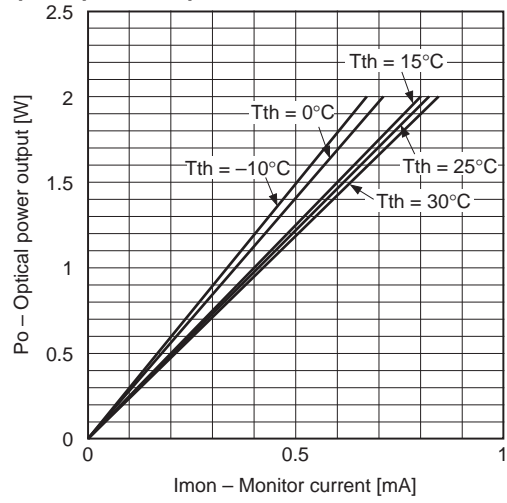


Example of Representative Characteristics

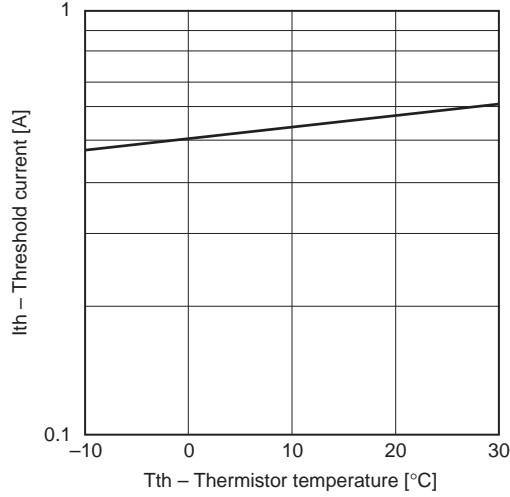
Optical power output vs. Forward current characteristics



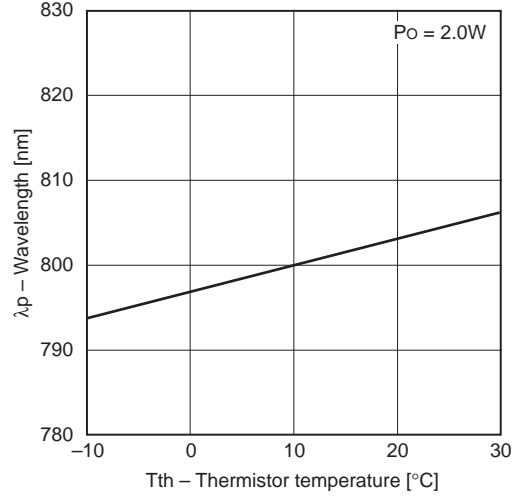
Optical power output vs. Monitor current characteristics



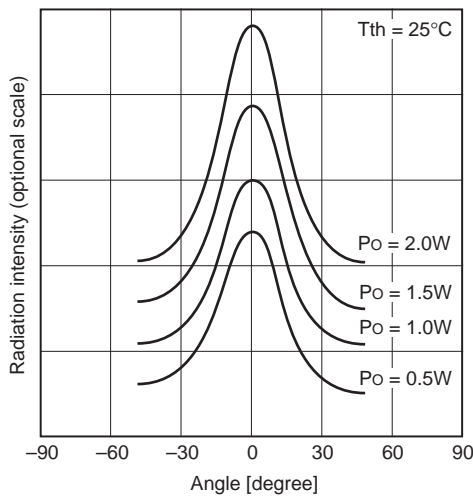
Threshold current vs. Temperature characteristics



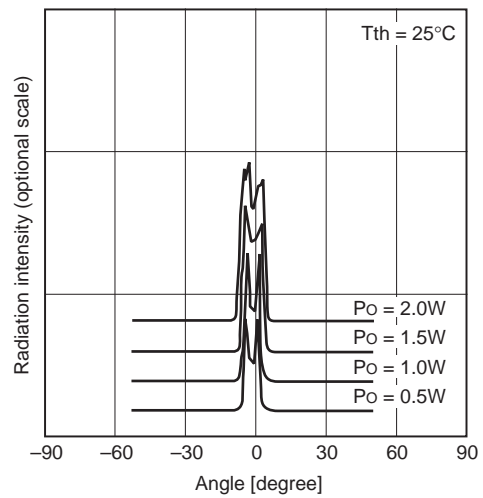
Dependence of wavelength



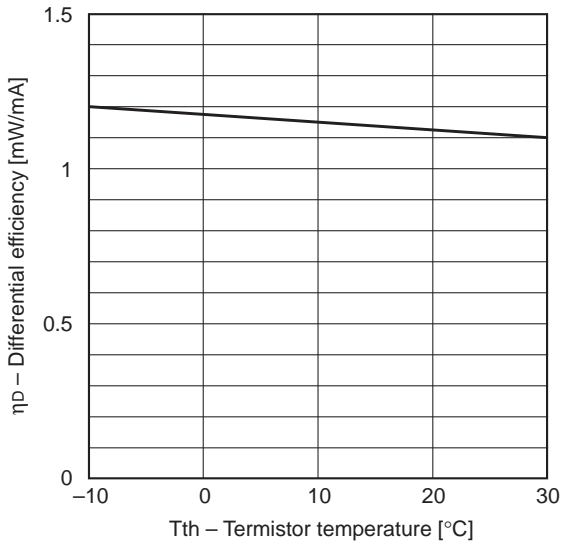
Power dependence of far field pattern (Perpendicular to junction)



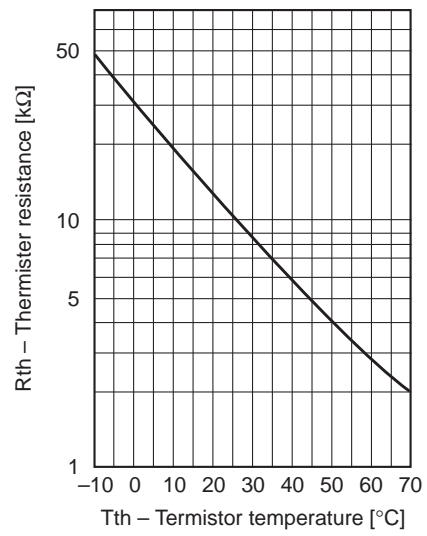
Power dependence of far field pattern (Parallel to junction)



Differential efficiency vs. Temperature characteristics

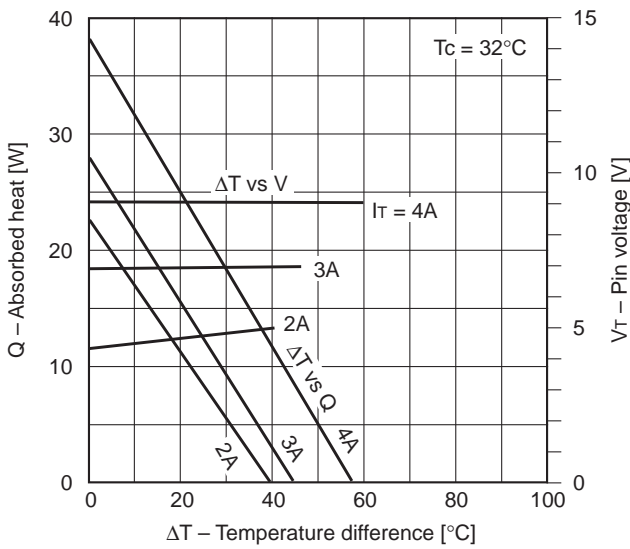


Termistor characteristics

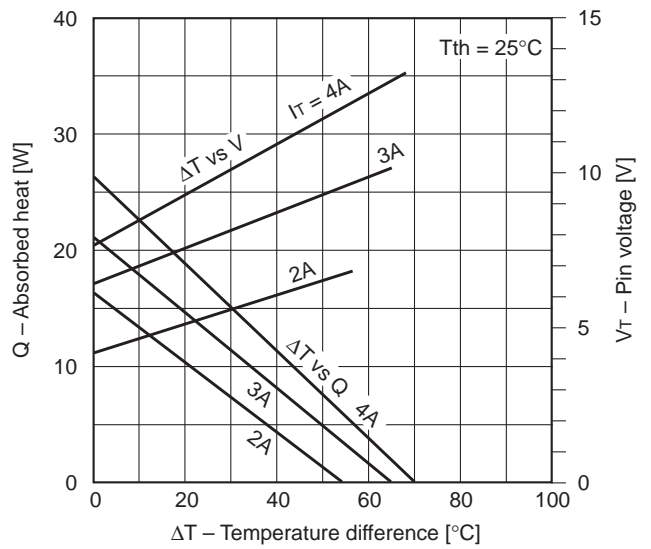


TE cooler characteristics

TE cooler characteristics 1

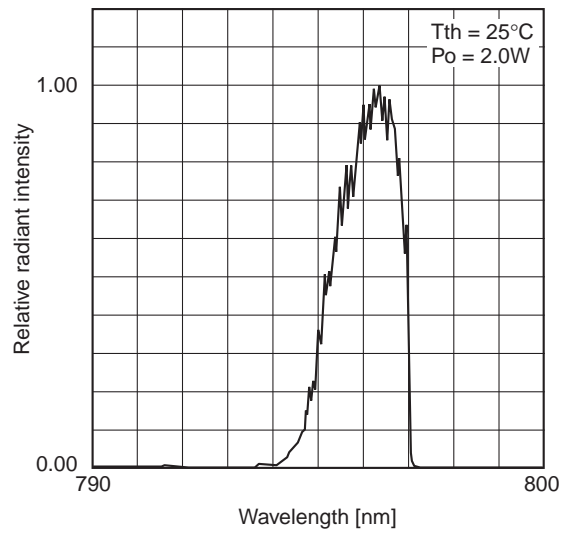
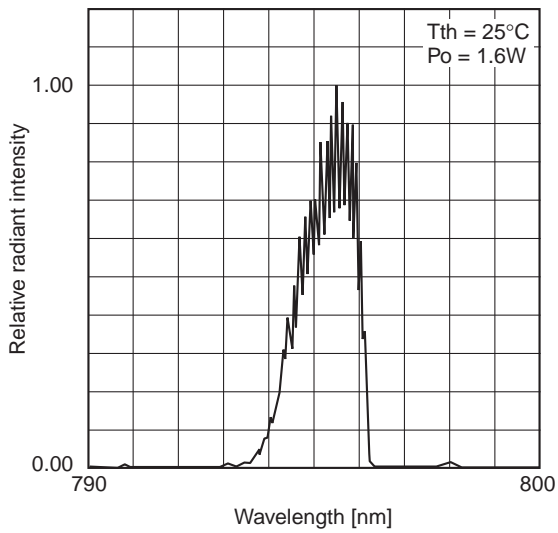
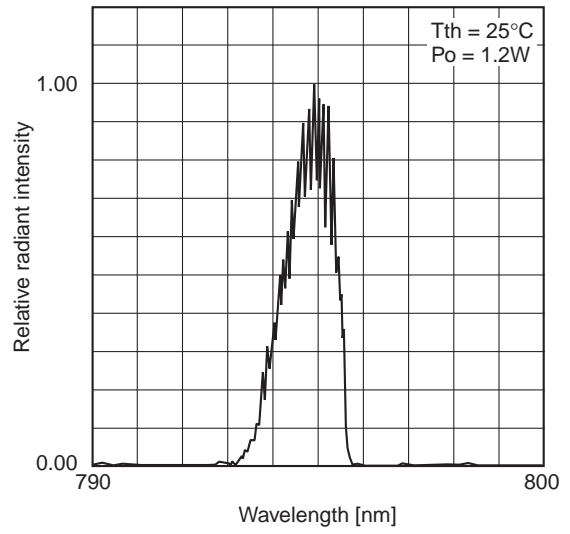
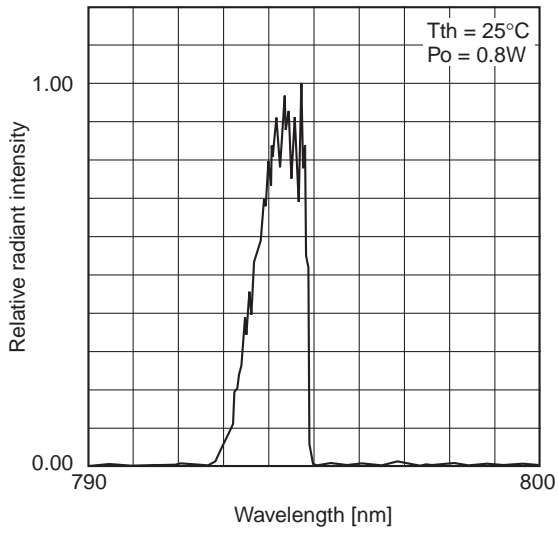


TE cooler characteristics 2

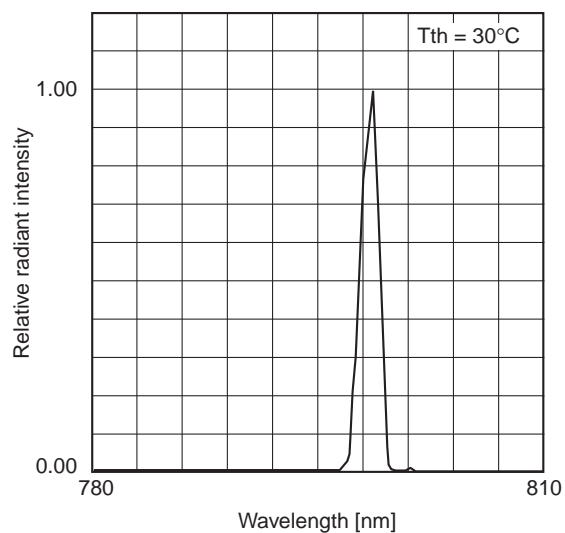
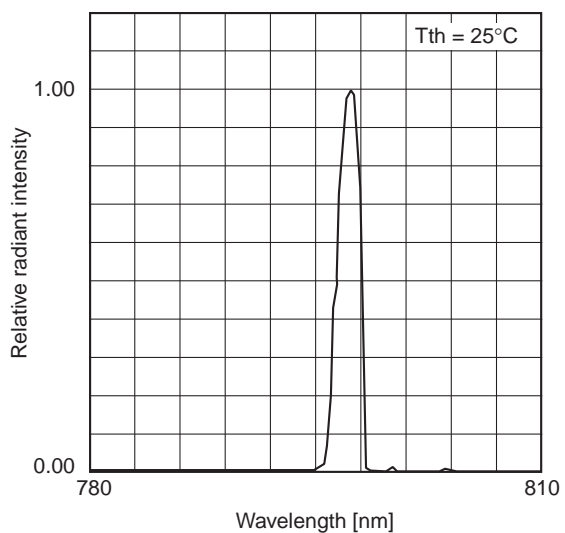
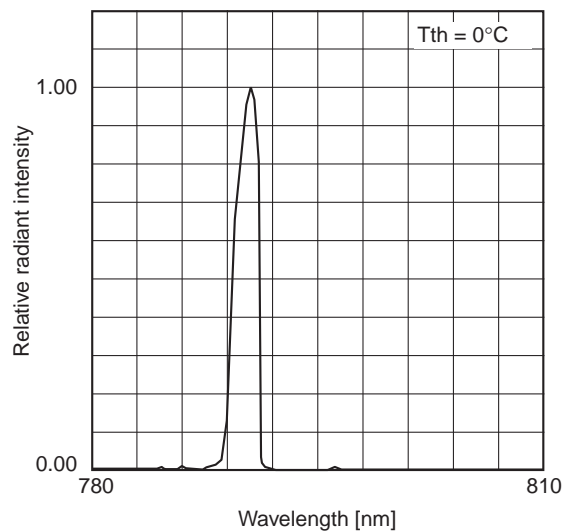
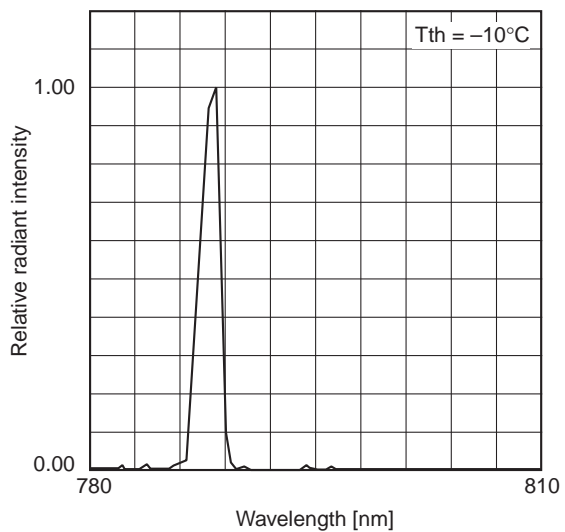


$\Delta T$ :  $T_c - T_{th}$   
 $T_{th}$ : Thermistor temperature  
 $T_c$ : Case temperature

Power dependence of spectrum



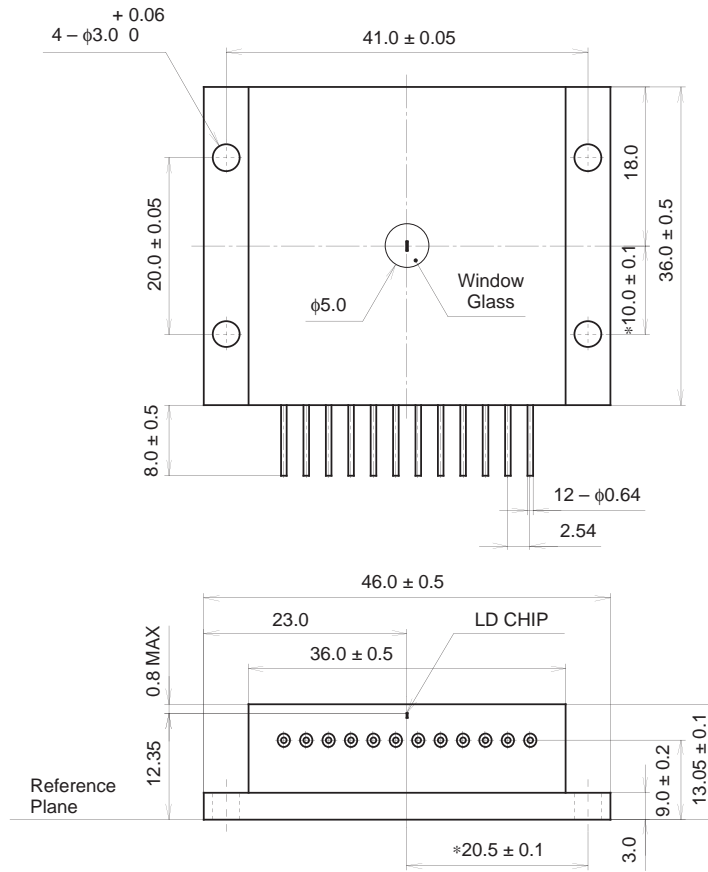
Temperature dependence of spectrum ( $P_o = 2W$ )



Package Outline

Unit: mm

M-272



\*Distance between pilot hole and emitting area.

SONY CODE	M-272
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE WEIGHT	118 g
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